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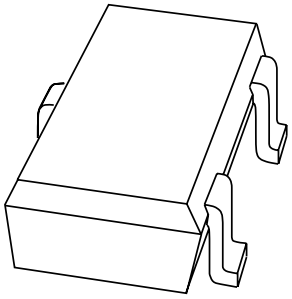
Team Nexperia

DATA SHEET



BFS20W
NPN medium frequency transistor

Product data sheet

1999 Apr 21

NPN medium frequency transistor BFS20W

FEATURES

- Low current (max. 25 mA)
- Low voltage (max. 20 V).
- Very low feedback capacitance (typ. 350 fF).

APPLICATIONS

- IF and VHF applications in thick and thin-film circuits.

DESCRIPTION

NPN medium frequency transistor in a SOT323 (SC-70) plastic package.

MARKING

TYPE NUMBER	MARKING CODE(1)
BFS20W	N1∗

Note

1. ∗ = -: Made in Hong Kong.
   ∗ = t: Made in Malaysia.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

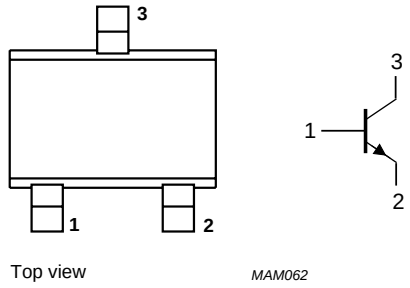


Fig.1 Simplified outline (SOT323; SC-70) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	30	V
V_{CEO}	collector-emitter voltage	open base	–	20	V
V_{EBO}	emitter-base voltage	open collector	–	4	V
I_C	collector current (DC)		–	25	mA
I_{CM}	peak collector current		–	25	mA
I_{BM}	peak base current		–	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	200	mW
T_{stg}	storage temperature		−65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		−65	+150	°C

Note

1. Refer to SOT323 (SC-70) standard mounting conditions.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	625	K/W

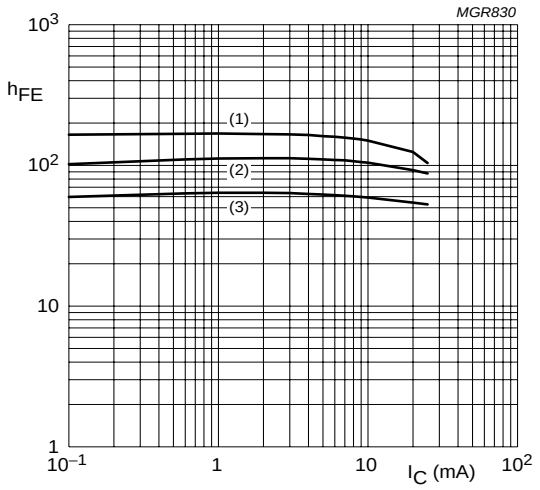
Note

1. Refer to SOT323 (SC-70) standard mounting conditions.

CHARACTERISTICS

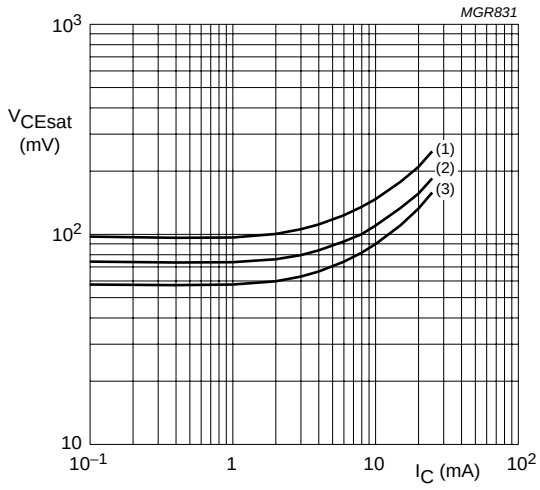
T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	I_E = 0; V_{CB} = 20 V	–	–	100	nA
		I_E = 0; V_{CB} = 20 V; T_j = 100 °C	–	–	10	μA
I_{EBO}	emitter cut-off current	I_C = 0; V_{EB} = 4 V	–	–	100	nA
h_{FE}	DC current gain	I_C = 7 mA; V_{CE} = 10 V	40	85	–	
V_{BE}	base-emitter voltage	I_C = 7 mA; V_{CE} = 10 V	–	740	900	mV
C_c	collector capacitance	$I_E = i_e$ = 0; V_{CB} = 10 V; f = 1 MHz	–	1	–	pF
C_{re}	feedback capacitance	I_C = 0; V_{CE} = 10 V; f = 1 MHz	–	350	–	fF
f_T	transition frequency	I_C = 5 mA; V_{CE} = 10 V; f = 100 MHz	360	470	–	MHz



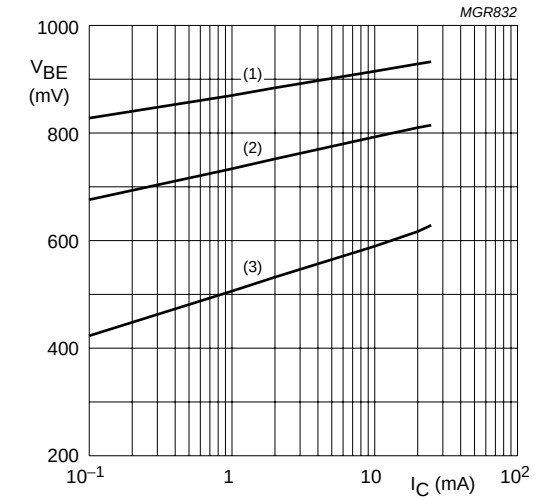
V_{CE} = 10 V.
(1) T_{amb} = 150 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = –55 °C.

Fig.2 DC current gain as a function of collector current; typical values.



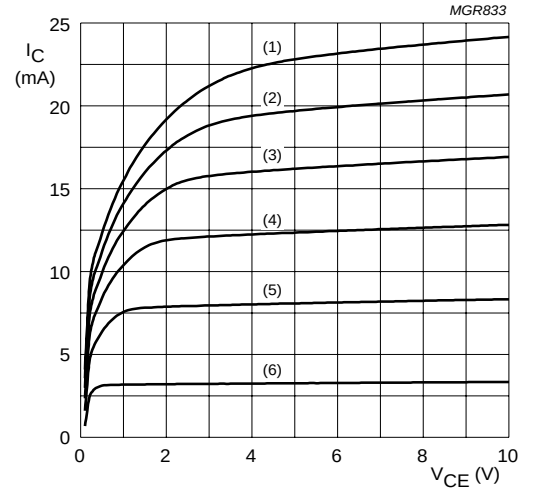
I_C/I_B = 10.
(1) T_{amb} = 100 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = –55 °C.

Fig.3 Collector-emitter saturation voltage as a function of collector current; typical values.



V_{CE} = 10 V.
(1) T_{amb} = –100 °C.
(2) T_{amb} = 25 °C.
(3) T_{amb} = 150 °C.

Fig.4 Base-emitter voltage as a function of collector current; typical values.

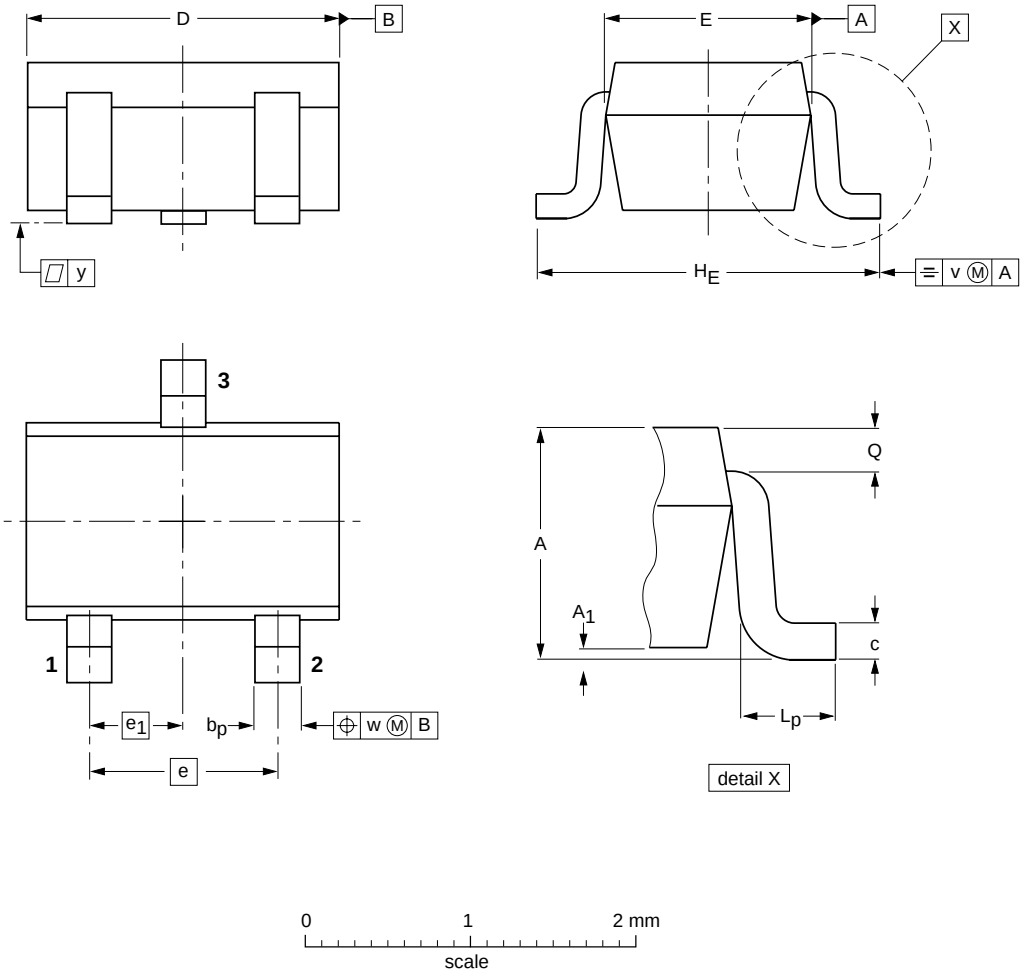


T_{amb} = 25 °C.
(1) I_B = 280 μA.
(2) I_B = 230 μA.
(3) I_B = 180 μA.
(4) I_B = 130 μA.
(5) I_B = 80 μA.
(6) I_B = 30 μA.

Fig.5 Collector current as a function of collector-emitter voltage; typical values.

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads **SOT323**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT323			SC-70			97-02-28

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

Customer notification

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Printed in The Netherlands 115002/00/01/pp7 Date of release: 1999 Apr 21 Document order number: 9397 750 05696

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